



### A brief history and first results May 20, 2004





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# Motivation

•While disturbing the beam as little as possible measure:

- •intensity
- •size/profile in 2 dimensions?
- timing between bunches or pulses

•The beam must be accurately measured in an environment with a lot of electromagnetic noise (high beam currents, solenoids, rf,...) and over a wide range of intensities.

Parameter	Minimum	Maximum	Unit
Beam Size ( $\pm 3\sigma$ ) at D.U.T.*	1	30	cm
Beam Divergence $^{\dagger}$ (±3\sigma) at D.U.T.*	±0.5	±14	mr
Number of Pulses per Second		15	
Number of Protons per Pulse	1.6	16	1012
Pulse Duration	5.0	50	μs

Muon Test Facility

### Polycrystalline CVD Diamond





Physical Property at 300 K	Diamond
band gap [eV]	5.45
Electron mobility [cm <sup>2</sup> /Vs]	2200
Hole mobility [cm <sup>2</sup> /Vs]	1600
Breakdown field [V/m]	$10^{7}$
Resistivity $\rho$ [ $\Omega$ cm]	$>10^{13}$
Dielectric constant $\varepsilon_r$	5.7
Thermal conductivity [W/cm K]	20
Lattice constant [Å]	3.57
Energy to remove an atom from the lattice [eV]	80
Energy to create an e-h pair [eV]	13

*induced charge:*  $dq = e \frac{dx}{L}$ 

 $dx = distance \ e - holes \ drift \ apart$  $dx = (\mu_{+}\tau_{+} + \mu_{-}\tau_{-})E$  $\mu = carrier \ mobility,$  $\tau = carrier \ lifetime$ 

Charge collection efficiency dependent upon: •grain boundaries •in-grain defects

high binding energy - makes it rad hard

high resistivity - allows it to maintain high E field

# My Gedankenexperiment

At 36 e-h pairs/um/mip the signal will be huge –too big! Possible solutions:

- •Turn down the voltage might compromise time resolution
- •Get material with rotten efficiency "black diamond" with small carrier  $\tau$
- •Get a killer power supply (literally) to maintain bias while drawing huge currents Agilent 6035A (1050 W)
- May be (somewhat) self modulating space charge, recombination...

#### The data you are about to see tests these hypotheses...

What about radiation effects?

•Starting with material with a poor efficiency –so hope that the change in density of trapping sites is less pronounced.

### Has yet to be addressed.

### Two diamond profilers have been tested in a beam...





Collection distance =100  $\mu$ m

Thickness = ~600 µm

Manufacturer = DeBeers

large signals due to relatively high efficiencies

Expensive (~\$1500/sq.cm)

# **Black**



Collection distance =40µm?

Thickness = ~300 µm

Manufacturer = Norton diamond?

larger number of charge trapping sites modulates large signals

shorter carrier lifetimes give better time response

much cheaper



several time constants in the circuit: τ=diamond (capacitor) x readout resistor

- 1 GHz bandwidth
- 400 ps rise time
- 10 GS/s sample rate





### **Argonne Chemistry Linac**

•20 MeV electrons

•Max intensity: 23 nC/pulse  $\approx 1.4 \times 10^{11} e^{-1}$ 

•Beam size ~1 cm at end of beampipe

•Pulse width can be varied from subnansecond to ~10 ns



### Four beamtests

3

Jan 15, 2004 Proof of principle
Jan 22, 2004 More rigorous studies



Ch4

500mV

M 20.0ns 2.5GS/s 400ps/pt A Ch1 🔨 -80.0m V



#### Longitudinal profile: time resolution smaller than the pulse width







## As a function of bias voltage and intensity





• Clear diamond has much bigger signals (no big surprise)

• Amplitude isn't linear as a function of intensity (uh-oh)

• But amplitude isn't the figure of merit, it is the amount of charge induced...



That is, the integrated area under the pulse...



Response much more linear as a function of intensity...



...but if the total charge is linear and the amplitude is not, then the pulses must be getting wider as a function of intensity!

ignal pulse width

#### for electron bunches of 4 ns nominal width



black diamond signal width is always the same as the 4ns bunch width

Conclusion: black diamond has better intrinsic resolution which is better than 4 ns

### What is the intrinsic time resolution of the black diamond?

•For this you need the Rolls Royce of scopes and mine is a mere Cadillac- borrowed a Tektronix 7404 with 4GHz bandwidth and 20 Gs/s sample rate

- •Tuned the beam up for subnanosecond pulses
- •Got a time profile of the beam using a fast Faraday cup
- •Compare to black diamond- fast rise time the narrowest measured pulse width is 2 ns
- •Dialed the intensity way down- this width does not seem to be intensity dependent
- •An effect of the thickness, perhaps???



## A few words on intensity and saturation

It was a major goal of mine to address this, but it really needs more study (or a better setup).



Based on geometrical arguments we estimate the maximum intensity we reached as follows:

full beam: 23 nC/pulse  $\approx 1.4 \times 10^{11} e^{-1}$ 

beam size at highest intensity point: 4 sq. cm  $\approx 3 \times 10^{10} e^{-} / cm^{2}$ 

> $\approx 2 \times 10^9 e^$ through 1/8" hole

At the highest intensity, the response changed when we tweaked the intensity...so I cautiously claim it wasn't saturated.



•Would like to try thinner "black" diamonds, we don't need the charge. (A German company, Fraunhofer Gesellschaft, claims they can provide free standing diamond in tens of microns thickness.)

•Would like to make studies more systematic (i.e. change only one variable, collection distance or thickness, at once). To this end, we tried to have a black diamond thinned. That failed.

•Need to work on understanding intensity.

•Need to study radiation effects in diamond with short carrier lifetimes.